# Revolutionize Your Surface Analysis with Fiber Optic Spectrometer for Film Thickness Measurement

#### **Basic Information**

Place of Origin: CHINA
Brand Name: JINSP
Certification: ISO9001
Model Number: SR100Q
Minimum Order Quantity: 1

Price: Negotiable

Packaging Details: International Shipping Pakcage

Delivery Time: 90-120 working days
 Payment Terms: T/T, Western Union
 Supply Ability: 100PCS/90-120 days



#### **Product Specification**

Spectrual Range: 200nm - 1100nmEffective Pixels: 1024\*122

• Qutuam Efficiency: QE92%peak@650nm, 83%@232nm

• SNR: 1000:1



#### More Images



#### 92% High Quantum Spectrometer for Film Thickness Measurement

In sectors dependent on thin film coatings, accurate thickness data ensures optimal product functionality. Photoelectric measurement systems offer the perfect balance of speed and safety. When enhanced with predictive algorithms, these technologies empower manufacturers to achieve new standards of efficiency and innovation.

The JINSP SR100Q spectrometer is integrated with the Hamamatsu S7031, a scientific-grade TE-cooled area array CCD chip. With a pixel size of up to 24\*24µm and excellent quantum efficiency of up to 92%, it ensures high response in the ultraviolet band and effectively improves the sensitivity and SNR of weak signals. Furthermore, it can realize excellent spectrum signals, and stable and reliable performance based on the advanced high-resolution light path and low-noise, high-speed FPGA signal processing chip.

#### **Product Parameters:**

Detector	Chip Type	Back-illuminated TE-cooled Hamamatsu S7031	
	Effective Pixel	1024*122	
	Pixel Size	24*24µm	
	Sensing Area	24.576*2.928mm	
Optical Parameters	Optical Design	F/4 cross-type	
	Numerical Aperture	0.13	
	Focal Length	100mm	
	Entrance Slit Width	10μm,25μm,50μm,100μm,200μm (customizable)	
	Fiber Interface	SMA905,free space	
Electrical Parameters	Integration Time	8ms-3600s	
	Data Output Interface	USB3.0,RS232,RS485,20pin connector	
	ADC Bit Depth	16-bit	
	Power Supply	5V	
	Operating Current	<3.5A	
Physical Parameters	Operating Temperature	10 ~40	
	Storage Temperature	-20 ~60	
	Operating Humidity	<90%RH (no condensation)	
	Dimensions	180mm*120mm*50mm	
	Weight	1.2kg	

#### **List of Product Models:**

Model	Spectral Range(nm)	Resolution(nm)	Slit(µm)
		6.8	200
SR100Q-G21	200~950	2.2	50
SR100Q-G22	350~1100	1.5	25
		1.0	10
SR100Q-G23	200~775	1.6	50
0.000	350~925	1.0	25
SR100Q-G24		0.7	10
SR100Q-G25	532~690(4400cm-1*)*	13cm-1	50
SR100Q-G26	638~800(3200cm-1)*	10cm-1	25
SR100Q-G27	785~1050(3200cm-1)*	11cm-1	50

Note: The\*are primarily designed for Raman applications, with the corresponding Raman.

#### **Technical Characteristics:**

High quantum efficiency, 92%peak@650nm, 83%@232nm

High SNR: Ultra-low dark noise under long integration time, SNR is as high as 1000:1

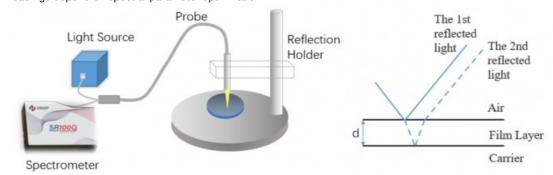
Noise-free clear processing of weak signal in long exposure, strong adaption to environment

Low-noise and high-speed circuit: USB3.0

#### **Measurement Method:**

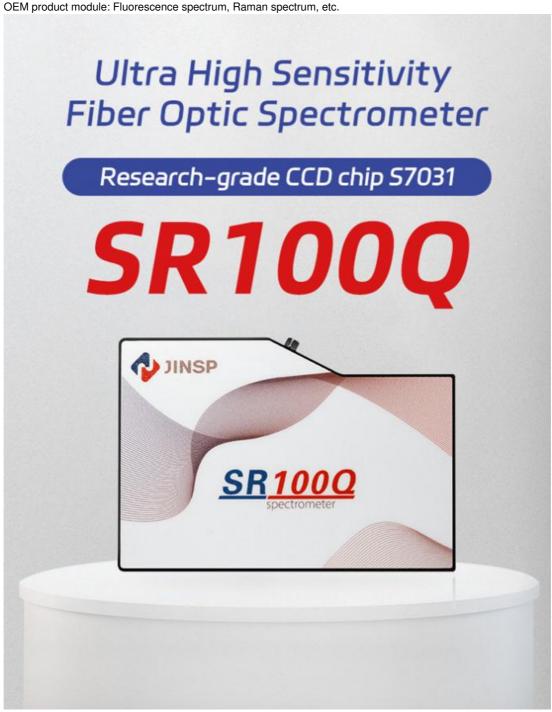
The system uses an optical fiber to project light onto the film, creating reflections at its upper and lower boundaries. The resulting interference spectrum, acquired by the spectrometer, facilitates thickness (d) computation via the extremum method (incorporating  $\theta$ , n, and spectral peaks/troughs). Fringe frequency rises with thickness but falls with wavelength. Accurate

readings depend on spectral parameter optimization.

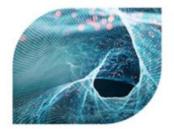


#### **Typical Applications:**

Detect absorption, transmittance and reflection Spectrum Light source and laser wavelength characterization OEM product module: Fluorescence spectrum. Raman spectrum, etc.



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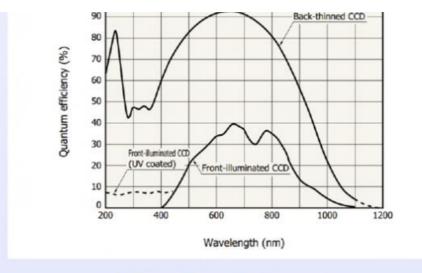


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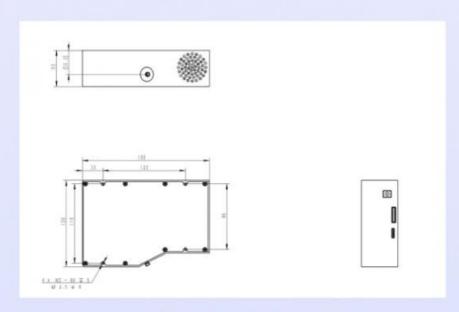


OEM product module: Fluorescence spectrum, Raman spectrum, etc.

(Typ. Ta=25 °C



#### CCD Quantum Efficiency Curve



Installation dimension drawing

#### **Company Introduction:**

JINSP Company Limited, abbreviated as "JINSP", is a professional supplier with over 17 years of experience in spectral detection technology products, including Raman, FT-IR, LIBS technologies, etc. After 17 years of technology accumulation, the company's core key technologies have reached the international leading position at the level, and the cumulative number of patent applications exceeded 200.

In addition to its main headquarters located in the bustling city of Beijing, JINSP has established a fully owned subsidiary manufacturing facility situated in the province of Jiangsu, China.

JINSP Company received ISO9001:2015, ISO14001:2015, and ISO45001:2018 certifications. JINSP can provide required certifications, such as certification by the Ministry of Public Security or National Institute of Metrology, Environmental Level Certification, IP Level Certification, CE Certification, Transport Identification Report, EU ECAC certification, German ICT Security Testing, etc.

# **Company Profile**









## **Exhibition**









# **Certifications**







#### FAQ

A1:We will send you manual and guide vedio in English, it can teach you how to operate the spectrometer. Also our technicians will offer professional tecnical opearation meetings.

Q2: Can your offer a operation traning?

A2: Your technicians can come to our factory for a training. Jinsp engineers can go to your place for local support (installation, training, debugging, maintenance).

Q3: What's your website?

A3:You can visit:www.jinsptech.com

Q4: What about your quality assurance?

A4: We have a quality inspection team. All goods will go through quality inspection before shipment. We can send you pictures for inspection.



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